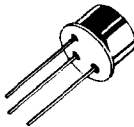
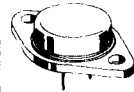


EPIFET power fet transistors transistors de puissance EPIFET



Type	P (W)	V _{DSS} (V)	I _{DSS} (μA)	I _D (A)	R _{DS(on)} / I _D (Ω)	I _D (A)	t _d max (ns)	t _r max (ns)	t _{d(off)} max (ns)	t _f max (ns)	Case
2N 6659 2N 6660 2N 6661	6,25 6,25 6,25	35 60 90	10 10 10	2 2 2	1,8 3 4	1 1 1	5 5 5	5 5 5	5 5 5	5 5 5	 TO-39 CB-7
2N 6656 2N 6657 2N 6658	25 25 25	35 60 90	10 10 10	2 2 2	1,8 3 4	1 1 1	5 5 5	5 5 5	5 5 5	5 5 5	 TO-3 CB-19
EPIFET : Epitaxial Power Insulated - FET											